

Ultra fast Rectifier

INCHANGE SEMICONDUCTOR

DSEP15-06AS

 FEATURES With TO-263 packaging Metal silicon junction, majority carrier conduction Low power loss, high efficiency Guardring for overvoltage protection High surge capability Minimum Lot-to-Lot variations for robust device performance and reliable operation 				1 2 3 D2PAK	Base cathode 4 4 0 2 Cathode 3 Anode TO-263 Packa	
APPLICA	TIONS			_		
Switchir	ng power supply			B		s
•	equency inverters				K -	
Reverse	e battery protection					
 Polarity 	protection applications			c		U
• Polarity	protection applications					W
	TE MAXIMUM RATINGS(Ta=25°C)				H R V	all a
ABSOLU'		VALUE	UNI T		H R V	dir.
ABSOLU'	TE MAXIMUM RATINGS(Ta=25℃)	VALUE 600	1		H R G V MIN MAX 10 6.6 6.8 15.23 15.25 10.15 10.17 0.76 0.78 1.26 1.28 1.4 1.6	dir M
ABSOLU SYMBOL VRRM VRRM VRMS	TE MAXIMUM RATINGS(Ta=25°C) PARAMETER Peak Repetitive Reverse Voltage RMS Voltage		Т		mm R V M MIN MAX 10 6.6 6.8 15.23 15.25 10.15 10.15 10.17 0.76 1.26 1.28 1.4 1.6 1.33 1.35 0.4 0.6 4.6 4.8	dir.
ABSOLU SYMBOL VRRM VRMS VR	TE MAXIMUM RATINGS(Ta=25°C) PARAMETER Peak Repetitive Reverse Voltage RMS Voltage DC Blocking Voltage	600	т ∨		mm R V M MIN MAX 10 6.6 6.8 15.23 15.25 10.15 10.17 0.76 0.78 1.26 1.28 1.4 1.6 1.33 1.35 0.4 0.6 4.6 4.8 8.69 8.71 5.28 5.30 1.26 1.28 1.28	all a
ABSOLU SYMBOL VRRM VRMS VR IF(AV)	TE MAXIMUM RATINGS(Ta=25°C) PARAMETER Peak Repetitive Reverse Voltage RMS Voltage DC Blocking Voltage Average Rectified Forward Current @Tc=140°C Nonrepetitive Peak Surge Current 10 ms single half sine-wave superimposed on	600 15	T V A		mm R V M MIN MAX 10 6.6 6.8 15.23 15.25 10.15 10.17 0.76 0.78 1.26 1.28 1.4 1.6 1.33 1.35 0.4 0.6 4.6 4.8 8.69 8.71 5.28 5.30 1.26 1.28 0.0 0.2 0.37 0.39 0.37 0.39	all a
ABSOLU SYMBOL VRRM VRMS VR IF(AV) IF(AV)	TE MAXIMUM RATINGS(Ta=25°C) PARAMETER Peak Repetitive Reverse Voltage RMS Voltage DC Blocking Voltage Average Rectified Forward Current @Tc=140°C Nonrepetitive Peak Surge Current 10 ms single half sine-wave superimposed on rated load conditions;One shot	600 15 110	T V A A		mm R V M MIN MAX 10 6.6 6.8 15.23 15.25 10.15 10.17 0.76 0.78 1.26 1.28 1.4 1.6 1.33 1.35 0.4 0.6 4.6 4.8 8.69 8.71 5.28 5.30 1.26 1.28 0.0 0.2 0.37 0.39	dir.

isc website: <u>www.iscsemi.com</u> ¹ *isc & iscsemi* is registered trademark



Ultra fast Rectifier

DSEP15-06AS

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.6	°C/W

ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤1%)

SYMBOL	PARAMETER	CONDITIONS	МАХ	UNIT
VF	Maximum Instantaneous Forward Voltage	IF= 15A;Tc= 25℃ IF= 15A;Tc= 150℃ IF= 30A;Tc= 25℃ IF= 30A;Tc= 150℃	2.04 1.35 2.25 1.59	V
I _R	Maximum Instantaneous Reverse Current	V _R = rated V _{RRM;} Tc= 25℃ Tc=150℃	100 500	μA
trr	Maximum Reverse Recovery Time	Iϝ =15A;dsIϝ/dt=200A/ μ s;V _R =300V	35	ns

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

isc website: <u>www.iscsemi.com</u>